

MAY 17 2004

OFFICIAL
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:)
 Hiroyuki Nitta et al.)
 Serial No.: 09/883,210)
 Filed: June 19, 2001)
 For: Semiconductor Device Having A)
 Wiring Layer Of Damascene)
 Structure And Method For)
 Manufacturing The Same)

Group Art Unit: 2815
 Examiner: J. Nguyen
 Atty. Dkt. No. 01701.00086

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CR Glembock
 Christopher R. Glembocki
 Reg. No. 38,800

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RESPONSE TO ELECTION REQUIREMENT

Assistant Commissioner of Patents
 Washington, D.C. 20231

Sir:

This paper is responsive to the Restriction Requirement mailed February 7, 2002, and to the Holding of Applicants response as non-responsive of March 22, 2002. This paper is filed within one month of the March 22, 2002, communication.

Applicants hereby elect Species V, relating to Figures 6A-6E, without traverse. Claims 1-4 and 10-15 correspond to Species V.

Applicant reserves the right to file a divisional application directed to the non-elected invention. A preliminary amendment is filed herewith under separate cover. Please charge any fee associated with the filing of this paper to our Deposit Account No. 19-0733.

Respectfully submitted,

By: *CR Glembock*

Joseph M. Potenza
 Registration No. 28,175

BANNER & WITCOFF, LTD.
 1001 G Street, N.W., 11th Floor
 Washington, D.C. 20001
 (202) 508-9100
 Dated: April 19, 2002

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AMENDMENT

Assistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please amend the application as follows:

In the Claims:

Please amend claim 4 as follows:

4. (Amended) The semiconductor device according to claim 1, further comprising:

a second insulation film formed above the space region, the second insulation film being different from the first insulation film; and

a third insulation film formed on a sidewall of the groove section, the third insulation film being different from the first and second insulation films.

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Christopher R. Glembocki
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AMENDMENTAssistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please amend the application as follows:

In the Claims:

Please amend claim 4 as follows:

4. (Amended) The semiconductor device according to claim 1, further comprising:

a second insulation film formed above the space region, the second insulation film being different from the first insulation film; and